

JL7086E Datasheet

Zhuhai Jieli Technology Co.,LTD

Version 1.3

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Revision History

Date	Revision	Description
2024.09.19	V1.0	Initial Release
2024.12.03	V1.1	Update Pin Description
2025.01.08	V1.2	Update Features_Bluetooth Update Block Diagram Update BT Characteristics
2025.06.13	V1.3	Update Datasheet Format Update Features_SYSTEM Update Package Information

Table of Contents

Revision History	1
Table of Contents	2
JL7086E Features	3
1 Block Diagram	4
2 Pin Definition	5
2.1 Pin Assignment	5
2.2 Pin Description	6
3 Electrical Characteristics	8
3.1 Absolute Maximum Ratings	8
3.2 ESD Ratings	8
3.3 PMU Characteristics	8
3.4 Battery Charge	9
3.5 IO Characteristics	9
3.6 BT Characteristics	11
4 Package Information	12
4.1 QFN32L_4×4mm	12
5 IC Marking Information	13
6 Solder-Reflow Condition	14

JL7086E Features

SYSTEM

- Dual Core 32bit DSP 192MHz
- With IEEE754 Single precision FPU
- Support FFT/MATRIX/MATH
- Support NPU
- 2 x I-cache and D-cache
- Support SDTAP/EMU
- On-chip SRAM 384kbyte
- Support MMU
- Support MPU
- Built-In Flash
- 24MHz crystal oscillator
- Internal RC oscillator, PLL

- 2 x Buck DC-DC converter
- Support temperature sensor
- VPWR range 4.5V to 5.5V
- VBAT range 2.7V to 4.5V
- IOVDD range 2.7V to 3.6V

Packages

- QFN32L(4mm*4mm)

Temperature

- Operating temperature
TC = -20℃ to +85℃ (standard range)
TC = -40℃ to +105℃ (extended range)
- Storage temperature -65℃ to +150℃

Bluetooth

- Dual-mode BT6.0 with LE Audio (DN Q332415)
- Support AoA/AoD
- Support LE audio BIS/CIS
- Support long range BLE
- Maximum transmitting power 13dBm
- Receiver sensitivity
 - ❖ -98dBm @BR
 - ❖ -98.5dBm @EDR $\pi/4$ DQPSK
 - ❖ -92.5dBm @EDR 8DPSK

Applications

- BT Dongle

Peripherals

- 1 x Full speed USB
- 6 x Multi-function 32bit timer
- 3 x UART interface
- 1 x I²C Master/Slave interface
- 1 x I²S/TDM/PDM Master/Slave interface
- 3 x SPI Master/Slave interface
- 1 x QDEC
- 4 x MCPWM
- 2 x Light strip controller
- 1 x 10bit ADC(6 Channels)
- 11 x GPIO Support function remapping
- 2 x LP_Touch with low power wake up

PMU

- Integrated battery charger up to 220mA

1 Block Diagram

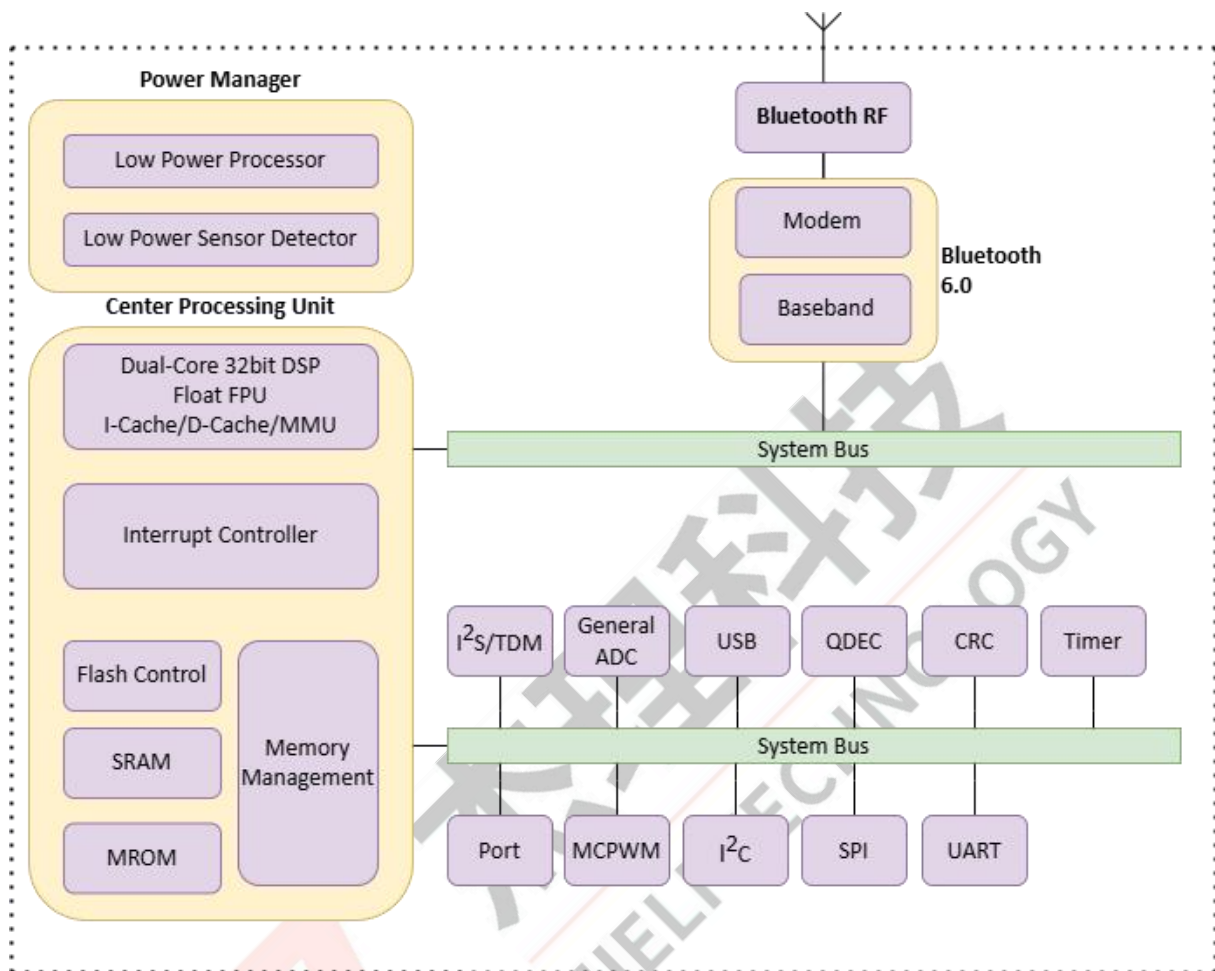


Figure 1-1 JL7086E Block Diagram

2 Pin Definition

2.1 Pin Assignment

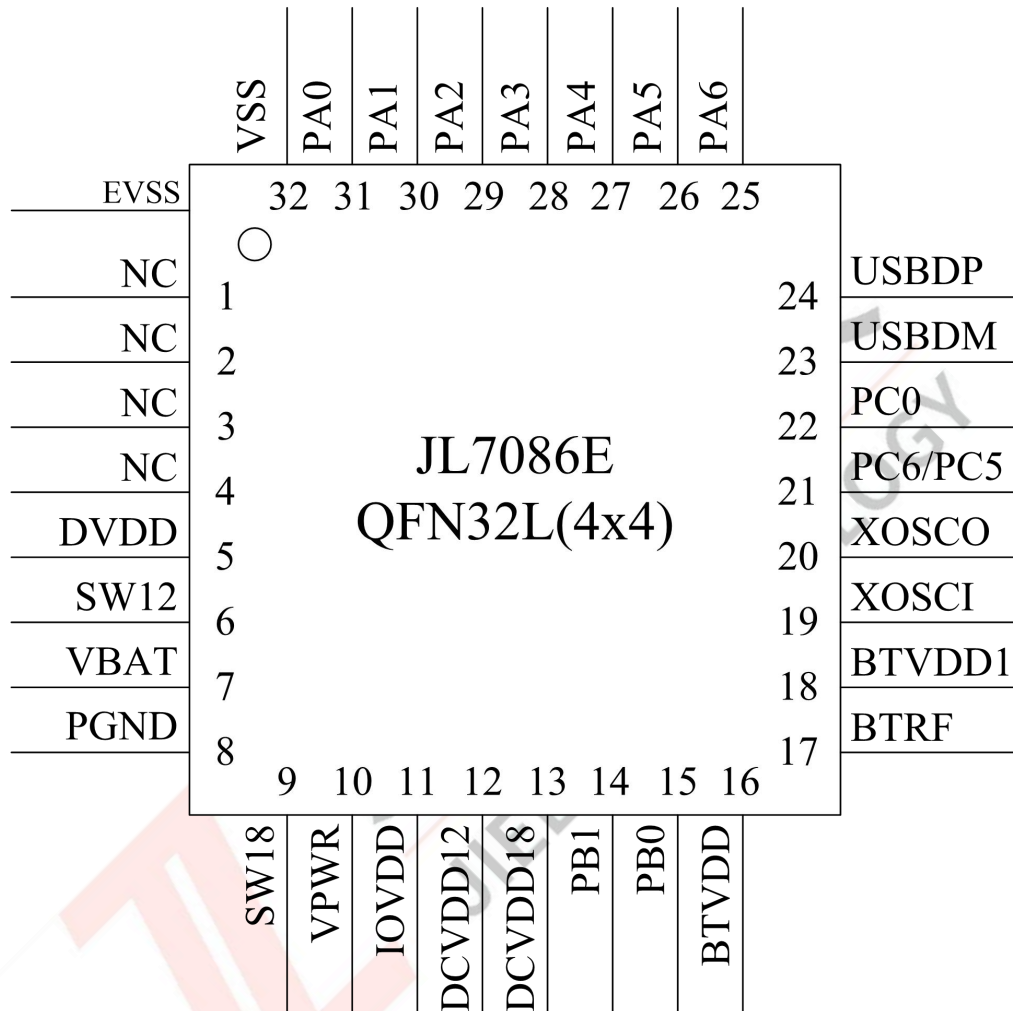


Figure 2-1 JL7086E Pin Assignment

2.2 Pin Description

Table 2-2-1 JL7086E Pin Description

Pin No.	Name	Type	IO Initial State	Description
1	NC	--	--	No Connection
2	NC	--	--	No Connection
3	NC	--	--	No Connection
4	NC	--	--	No Connection
5	DVDD	P	--	Digital Power
6	SW12	P	--	1.2V Buck DCDC Switch Port
7	VBAT	P	--	Battery Input
8	PGND	G	--	Ground of Buck DC-DC converter
9	SW18	P	--	1.8V Buck DCDC Switch Port
10	VPWR	P	Z	Charge Power Input
11	IOVDD	P	--	3.0V Power
12	DCVDD12	P	--	1.2V Power
13	DCVDD18	P	--	1.8V Power
14	PB1	I/O	10kΩ Pull-up	ADC2(ADC Input Channel 2) LP_TOUCH1(TOUCH_CH1) Hold down 0 to reset
15	PB0	I/O	Z	ADC1(ADC Input Channel 1) LP_TOUCH0(TOUCH_CH0) LVD(External Low Voltage Detection Input)
16	BTVD	P	--	BT Power
17	BTRF	RF	--	Bluetooth RF Antenna
18	BTVD1	P	--	BT Power
19	XOSCI	I	--	Crystal Oscillator Input
20	XOSCO	O	--	Crystal Oscillator Output
21	PC6	I/O	Z	--
	PC5	I/O	Z	ADC10(ADC Input Channel 10)
22	PC0	I/O	Z	--
23	USBDM	I/O	15kΩ Pull-down	USB Negative Data ADC15(ADC Input Channel 15)
24	USBDP	I/O	15kΩ Pull-down	USB Positive Data ADC14(ADC Input Channel 14)
25	PA6	I/O	Z	--
26	PA5	I/O	Z	--
27	PA4	I/O	Z	--
28	PA3	I/O	Z	--
29	PA2	I/O	Z	--
30	PA1	I/O	Z	--

Pin No.	Name	Type	IO Initial State	Description
31	PA0	I/O	Z	ADC0(ADC Input Channel 0)
32	VSS	G	--	Ground

Note

1.IO initial state abbreviations Z--High resistance, H--High level, L--Low level, X--May be changed during power on.

2.Timer, MCPWM, QDEC, UART, LEDC, I²C, I²S, and SPI functions can be remapped to any I/O.

Table 2-2-2 Pin types description

Pin Type	Description	Pin Type	Description
P	Power	I/O	Input or Output
G	Ground	I	Input
RF	RF antenna	O	Output

3 Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1 Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-20	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	4.5	V
VPWR		-0.3	6.0	V
IOVDD		-0.3	3.6	V
DCVDD12		-0.3	1.3	V
DCVDD18		-0.3	2.0	V
BTVDD		-0.3	2.0	V
BTVDD1		-0.3	1.3	V
GPIO	Input voltage of GPIO (except PC0/PC6)	-0.3	3.6	V
HVTIO	Input voltage of HVT-IO (PC0/PC6)	-0.3	5.5	V

Note

1.Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device.

3.2 ESD Ratings

Table 3-2 ESD Ratings

Parameter	Typ	Test pin	Reference standard
Human Body Mode	±4kV	All pins	JEDEC EIA/JESD22-A114
Machine Mode	±200V	All pins	JEDEC EIA/JESD22-A115
Charge Device Model	±1kV	All pins	ANSI/ESDA/JEDEC JS-002-2022

3.3 PMU Characteristics

Table 3-3 PMU Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
VBAT	Power supply	--	2.7	3.7	4.5	V
VPWR	Power supply	--	4.5	5.0	5.5	V
Operating mode						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
IOVDD	Voltage output	--	--	3.0	--	V
	Loading current	IOVDD=3.0V@VBAT = 3.7V	--	--	200	mA
DCVDD12	Voltage output	--	--	1.2	--	V
	Loading current	DCVDD12=1.2V@VBAT = 3.7V	--	--	150	mA
DCVDD18	Voltage output	--	--	1.8	--	V
	Loading current	DCVDD18=1.8V@VBAT = 3.7V	--	--	180	mA

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Low Power mode						
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
IOVDD	Loading current	IOVDD=3.0V@VBAT = 3.7V	--	--	20	mA

3.4 Battery Charge

Table 3-4 Charger Characteristics

Symbol	Parameter	Min	Typ	Max	Unit
VPWR	Charge Input Voltage	VBAT+0.1V	5.0	5.5	V
CV	CV Mode Voltage Accuracy	4.175	4.2	4.225	V
		4.325	4.35	4.375	V
CC	CC Mode Current	20	--	220	mA
I _{end}	End Of Charge Current	2	--	22	mA
V _{Trickl}	Trickle Charge Voltage	--	3.0	--	V

3.5 IO Characteristics

Table 3-5 IO Characteristics

Input Characteristics						
Symbol	Parameter	Conditions	IO	Min	Max	Unit
V _{IL}	Low-Level Input Voltage	IOVDD = 3.0V	PA0~PA6 PB0,PB1 PC0,PC5,PC6 USBDP USBDM VPWR	-0.3	1.4	V
V _{IH}	High-Level Input Voltage	IOVDD = 3.0V	PA0~PA6 PB0,PB1 PC5 USBDP USBDM	1.7	3.3	V
		IOVDD = 3.0V	PC0 PC6 VPWR	1.7	5.5	V
Output Characteristics						
Symbol	Parameter	Conditions	IO	Typ		Unit
I _{OL}	Output Current	IOVDD = 3.0V Voutput = 0.3V	PA0~PA6 PB0,PB1 PC5	2(HD=0) 8(HD=1) 26(HD=2) 50(HD=3)		mA

		IOVDD = 3.0V Voutput = 0.3V	PC0 PC6 USBDP USBDM	8	mA
		IOVDD = 3.0V Voutput = 0.3V	VPWR	2	mA
I _{OH}	Output Current	IOVDD = 3.0V Voutput = 2.7V	PA0~PA6 PB0,PB1 PC5	2(HD=0) 8(HD=1) 26(HD=2) 50(HD=3)	mA
		IOVDD = 3.0V Voutput = 2.7V	PC0 PC6 USBDP USBDM	8	mA
		IOVDD = 3.0V Voutput = 2.7V	VPWR	2	mA
Internal Resistance Characteristics					
Symbol	Parameter	Conditions	IO	Typ	Unit
R _{pu}	Pull-up Resistance	IOVDD = 3.0V	PA0~PA6 PB0,PB1 PC0,PC5,PC6 VPWR	10k(PU=1) 100k(PU=2) 1M(PU=3)	Ω
		IOVDD = 3.0V	USBDP	1.5k	Ω
		IOVDD = 3.0V	USBDM	180k	Ω
R _{pd}	Pull-down Resistance	IOVDD = 3.0V	PA0~PA6 PB0,PB1 PC0,PC5,PC6 VPWR	10k(PD=1) 100k(PD=2) 1M(PD=3)	Ω
		IOVDD = 3.0V	USBDP USBDM	15k	Ω

Note

1.Internal pull-up/pull-down resistance accuracy ±20%

3.6 BT Characteristics

3.6.1 Transmitter

Table 3-6-1-1 Transmitter characteristics under BTVDD 1.8V

Parameter	Conditions	Min	Typ	Max	Unit
Maximum RF Transmit Power	BR	--	10	13	dBm
Maximum RF Transmit Power	EDR $\pi/4$ DQPSK EDR 8DPSK	--	10	--	dBm
Relative Transmit Power	EDR $\pi/4$ DQPSK EDR 8DPSK	--	-3	--	dB
Maximum RF Transmit Power	BLE-1Mbps	--	10	13	dBm
Maximum RF Transmit Power	BLE-2Mbps	--	10	13	dBm

Table 3-6-1-2 Transmitter characteristics under BTVDD 1.2V

Parameter	Conditions	Min	Typ	Max	Unit
Maximum RF Transmit Power	BR	--	7	10	dBm
Maximum RF Transmit Power	EDR $\pi/4$ DQPSK EDR 8DPSK	--	7	--	dBm
Relative Transmit Power	EDR $\pi/4$ DQPSK EDR 8DPSK	--	-3	--	dB
Maximum RF Transmit Power	BLE-1Mbps	--	7	10	dBm
Maximum RF Transmit Power	BLE-2Mbps	--	7	10	dBm

3.6.2 Receiver

Table 3-6-2 Receiver characteristics

Parameter	Conditions	Min	Typ	Max	Unit
Sensitivity	BR	--	-98	--	dBm
	EDR $\pi/4$ DQPSK	--	-98.5	--	dBm
	EDR 8DPSK	--	-92.5	--	dBm
	BLE-1Mbps	--	-101	--	dBm
	BLE-2Mbps	--	-97.5	--	dBm
	BLE-S2	--	-104	--	dBm
	BLE-S8	--	-109	--	dBm

4 Package Information

4.1 QFN32L_4×4mm

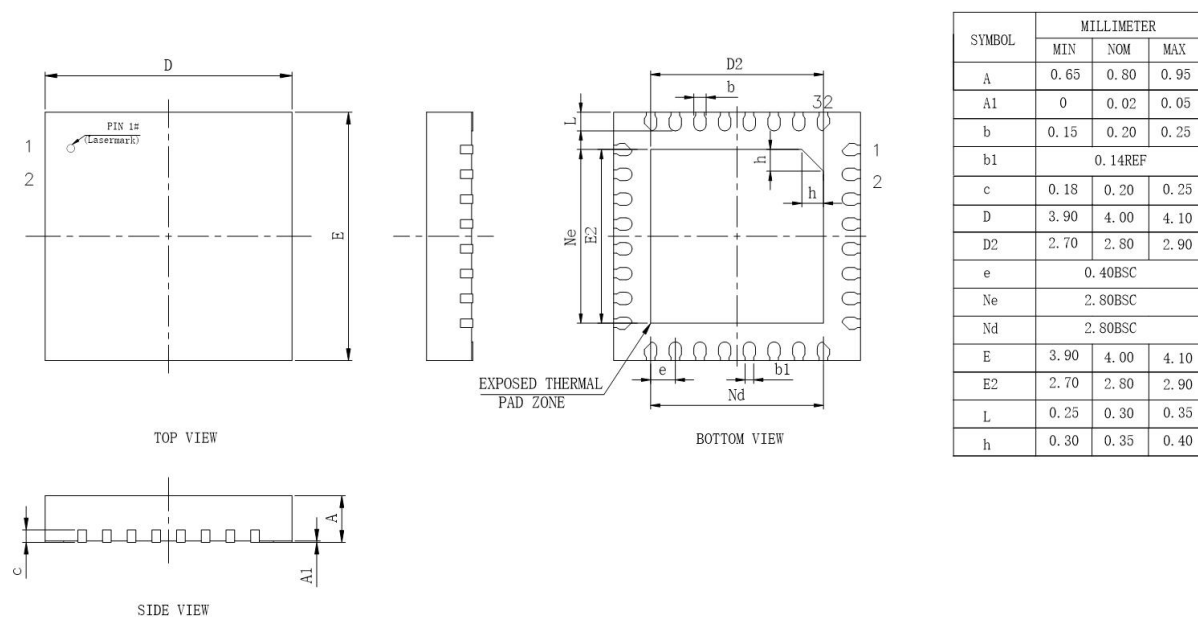


Figure 4-1 JL7086E Package

5 IC Marking Information

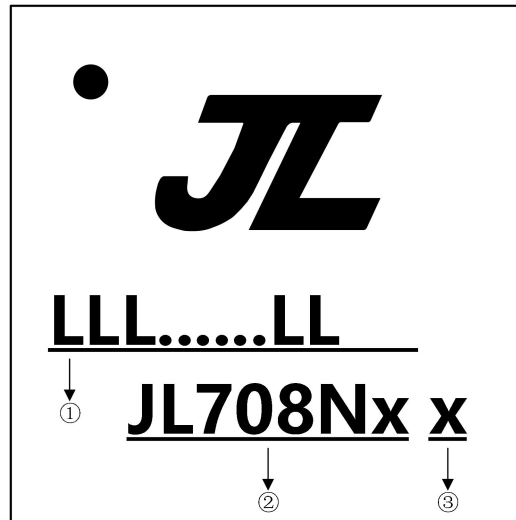


Figure 5-1 JL7086E Package Outline

- ① LLL.....LL: LOT No. , It contains 7 to 18 alphanumerics
- ② JL708Nx Chip Model
- ③ x Built-in flash size
 - 0 No Flash Memory
 - 2 2Mbit Flash
 - 4 4Mbit Flash
 - 8 8Mbit Flash
 - 6 16Mbit Flash
 - 3 32Mbit Flash

6 Solder-Reflow Condition

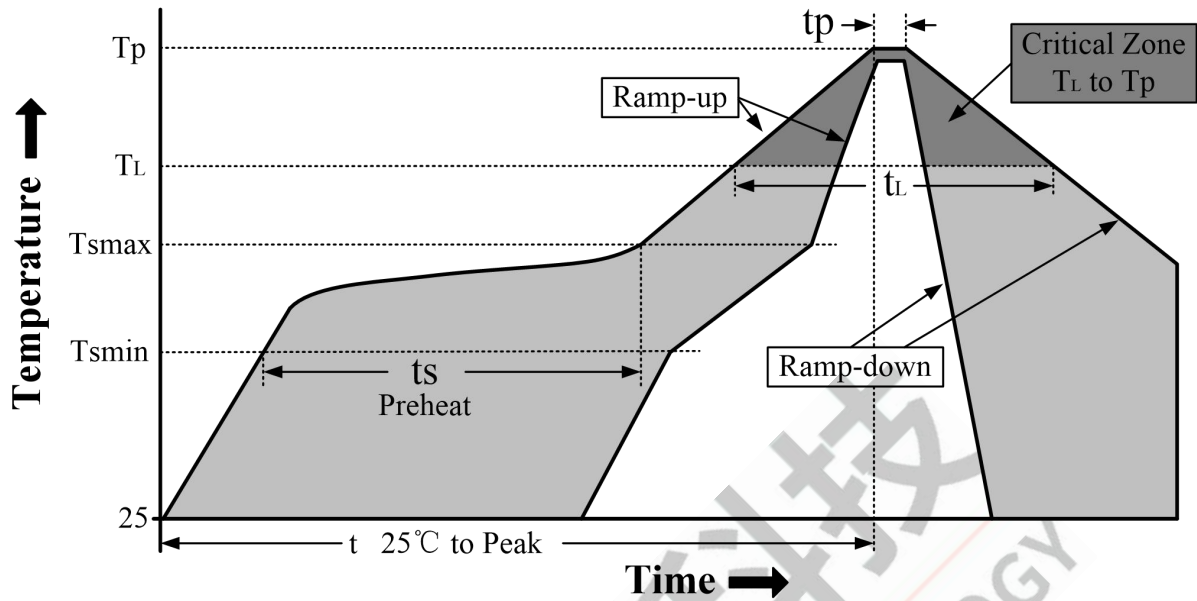


Figure 6-1 Classification Reflow Profile

Table 6-1 Classification Profiles

Profile Feature		Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat/Soak	Temperature Min (T_{smin})	100°C	150°C
	Temperature Max (T_{smax})	150°C	200°C
	Time (ts) from (T_{smin} to T_{smax})	60-120 seconds	60-180 seconds
Average ramp-up rate (T_{smax} to T_p)		3°C/second max	3°C/second max
Liquidous temperature (T_L)		183°C	217°C
Time (t_L) maintained above T_L		60-150 seconds	60-150 seconds
Peak package body temperature (T_p)		See Table 6-2	See Table 6-3
Time within 5°C of actual Peak Temperature (tp) ²		10-30 seconds	20-40 seconds
Ramp-down rate (T_p to T_L)		6°C/second max	6°C/second max
Time 25°C to peak temperature		6 minutes max	8 minutes max

Note

- 1.All temperatures refer to topside of the package, measured on the package body surface
- 2.Time within 5°C of actual peak temperature (tp) specified for the reflow profiles is a “supplier” and “user” maximum.

Table 6-2 SnPb Classification Temperature

Package Thickness	Volume mm ³ < 350	Volume mm ³ ≥ 350
<2.5 mm	240 +0/-5°C	225 +0/-5°C
≥2.5 mm	225 +0/-5°C	225 +0/-5°C

Table 6-3 Pb-free - Classification Temperature

Package Thickness	Volume mm ³ < 350	Volume mm ³ 350 - 2000	Volume mm ³ > 2000
< 1.6mm	260°C	260°C	260°C
1.6 mm - 2.5mm	260°C	250°C	245°C
> 2.5mm	250°C	245°C	245°C

Note

1.*Tolerance The device manufacturer/supplier shall assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0°C.For example 260°C+0°C)at the rated MSL level.